



Electronic structure and magnetism on FeSiAl alloy: A DFT study



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ABSTRACT

Density functional theory (DFT) calculation has been performed to study the electronic structure and chemical bonding in FeSiAl alloy. These calculations are useful to understand the magnetic properties of this alloy. Our results show that the mean magnetic moment of Fe atoms decreases due to the crystal structure and the effect of Si and Al. Depending on the environment, the magnetic moment of one Fe site (Fe_1) increases to about 14.3% while of the other site (Fe_2) decreases to about 25.9% (compared with pure bcc Fe). All metal–metal overlap interactions are bonding and slightly weaker than those found in the bcc Fe structure. The electronic structure (DOS) shows an important hybridization among Fe, Si and Al atoms, thus making asymmetric the PDOS with a very slight polarization of Al and Si atoms. Our study explains the importance of crystal structure in determining the magnetic properties of the alloys. FeSiAl is a good candidate for electromagnetic interference shielding combining low price and good mechanical and magnetic properties.

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1. Introduction

With the exponential growth of the mobile communication and computer technologies in the past three decades, the need of high-speed data transmission systems also grew. This kind of technology involves the use of microwaves of ultra high frequency (UHF) in the range of 0.3–3 GHz and super high frequency (SHF) in the range of 3–30 GHz. As a result, our environment is actually polluted by these electromagnetic waves of high frequencies. The risk posed by these high frequencies to human health and electrical equipment has drawn the interest of many researchers, who started to investigate different materials for the development of wave absorbers for this particular range of frequencies [1–4].

Electromagnetic interference (EMI) shielding offers an effective way to deal with wave-polluted environments. Conventional microwave absorption materials used for this purpose are typically made of metal powders such as iron, cobalt, nickel, metal alloys and ferrites. These materials present the drawback of being expensive and quite heavy, which restricts their use in applications requiring low price and lightweight mass. The conventional shielding materials fixed on electronic devices may interfere with the electrical circuits.

The manufacturing of absorbing/shielding materials with “thin, lightweight, wide, and strong” characteristic will efficiently

overcome the above mentioned problems. Incident microwaves are attenuated thanks to these materials and the microwaves reflected become much weaker as compared to the incident waves reflected from traditional shielding materials [5].

Fe_3Si and Fe_3Al alloys have excellent soft magnetic properties and they are widely used in different applications. Although these two alloys are isomorphous, they present very different mechanical properties; Fe_3Si is brittle, whereas Fe_3Al is ductile [6]. In order to improve their mechanical and magnetic properties, researchers have mixed these two binary alloys into FeSiAl. Many authors have reported important changes in the structural and magnetic properties of this new alloy compared to the Fe_3Si and Fe_3Al . Legarra et al. [7] reported that the Si substitution on the FeAl prevents the disorder of the alloy. FeAlSi crystallizes in the DO3-type structure [8,9]. The crystal structure is very important in determining the magnetic properties of the alloys. The effect of Si in the FeAl alloys is twofold; Si contributes to the decrease of the lattice parameter which, as reported by Nogues et al. [10], is of major importance for the magnetism, and, on the other hand, having one more p electron than the Al atom promotes the charge transfer from Si to Fe atoms, as reported by Legarrara et al. [11]. These two effects make the magnetism decrease: lattice parameter decrease makes the magnetism weaker due to the decrease in the charge transfer between the Al–Si and Fe atoms. The introduction of an additional electron from Si makes the hybridization higher getting a lower magnetic moment [12].

The dependence of dynamic magnetization, magneto-transport properties and thermal stability of FeAlSi films with oblique sputtering was studied via spin rectification effect [13,14].

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Mössbauer spectroscopy was used to understand the enhanced microwave permeability of Fe–Si–Al particles. This study reveals that flaky particles have an average magnetic moment of $1.63 \mu_B$ [15].

The aim of the present work is to analyze the electronic, band structure and chemical bonding of the FeSiAl alloy and to compare it with the results obtained for the pure bcc Fe.

2. Calculation methods and models

The FeSiAl alloy has DO3-type crystal structure, as shown in Fig. 1a, which is composed of four interpenetrating fcc lattices shifted by $1/4$ th of the main diagonal. These sublattices are abbreviated as A, B, C and D and originated at $(0, 0, 0)$, $(1/2, 1/2, 1/2)$, $(1/4, 1/4, 1/4)$, $(3/4, 3/4, 3/4)$. The A and C sublattices are symmetrically equivalent in DO3-type structure [6,16].

First principles calculations were performed using density functional theory (DFT) as implemented in the VASP code [17–19]. The exchange and correlation energies were calculated with the Perdew–Burke–Ernzerhof form of the spin-polarized generalized gradient approximation (GGA-PBE) [20]. Spin-polarization and non-linear core corrections [21] were included in the calculations for systems with Fe to correctly account for its magnetic properties. The electron–ionic core interaction was represented by ultrasoft pseudopotentials [22]. Valence atomic configurations are $3d^6 4s^2$ for Fe, $3s^2 3p^1$ for Al and $3s^2 3p^2$ for Si atom. A plane-wave basis with energy cutoff of 380 eV was used to expand the electronic wave functions. Brillouin zone integrations were performed on a $12 \times 12 \times 12$ special k-points mesh generated by the

Monkhorst–Pack scheme [23]. In order to accelerate the convergence, for fractional occupancies the first order Methfessel–Paxton [24] method with the Fermi surface smearing of 0.2 eV was adopted. The positions of all atoms were fully optimized until the forces on each atom were less than $0.02 \text{ eV}/\text{Å}$. Test calculations for denser k-point meshes do not show significant improvement. The crystal structure was simulated using a 2-atom unit-cell for bcc Fe and a 16-atom unit-cell for the FeSiAl. Calculations for the lattice constant of bcc Fe give a value of 2.846 Å (2.867 Å , [25]), and the bulk modulus of 167 GPa (170 GPa, [25]) in a very good agreement with experimental data (quoted in the parenthesis). In addition, the local spin magnetic moment of $2.24 \mu_B$ (Bohr magneton) for bcc Fe is in excellent agreement with previous calculations [26,27]. The approach used here is similar to that reported by Hung et al., giving a good description of bulk properties of bcc Fe [28]. In the case of the FeSiAl DO3 crystal structure the calculated lattice constant is 5.750 Å , which is in the range of values reported in the literature [12]. Bader analysis was used to calculate magnetic moments and electronic structure [29].

In order to understand the metal–metal interactions we have used the concept of density of states (DOS) and crystal orbital overlap population (COOP). The DOS curve is a plot of the number of orbitals as a function of the energy. The integral of the DOS curve over an energy interval gives the number of one-electron states in that interval; the integral up to the Fermi level (E_F) gives the total number of occupied molecular orbitals. If the DOS is weighed with the overlap population between two atoms the crystal orbital overlap population COOP is obtained. The integration of the COOP curve up to E_F gives the total overlap population of the specified bond orbital and it is a measure of the bond

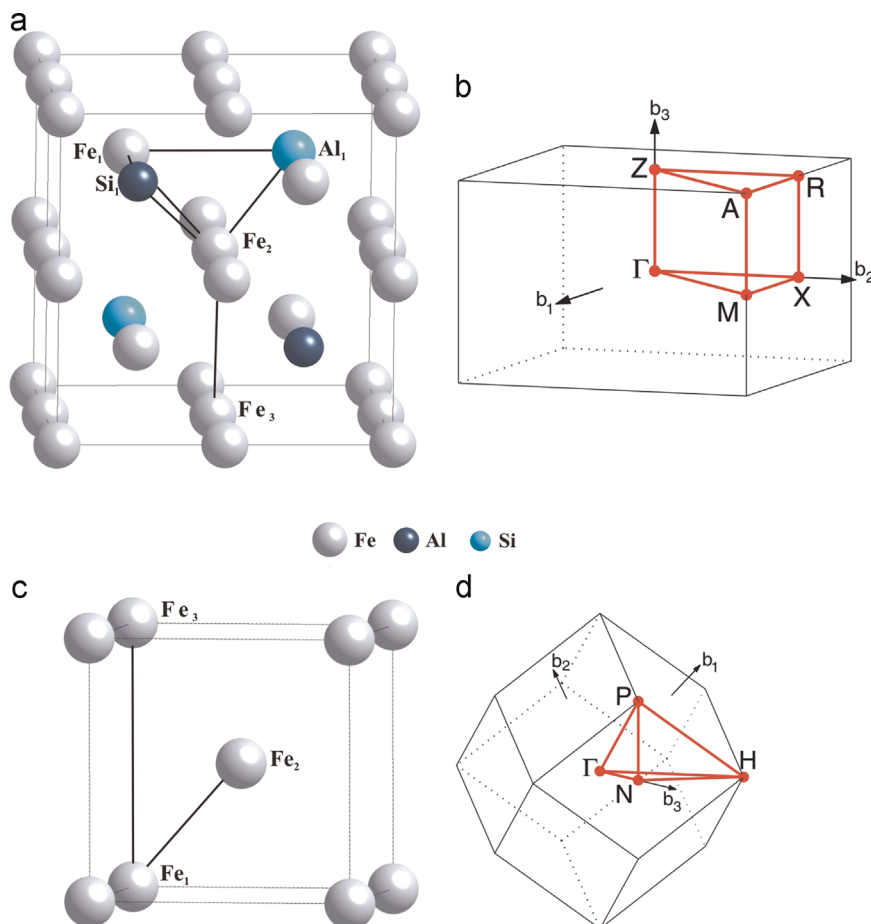


Fig. 1. Crystal structure and reciprocal space of FeSiAl (a, b) and bcc Fe (c, d).

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